

SN65HVD61

SLLS770D - JANUARY 2007 - REVISED JUNE 2011

ControlNet[™] TRANSCEIVER

Check for Samples: SN65HVD61

FEATURES

- Compatible With the ControlNet Standard
- I/O Operates From 2.5-V to 5-V Supply
- Receiver thresholds within –120mV to 120mV
- Receiver hysteresis >50mV
- Low Power Standby Mode
- Thermal Shutdown Protection
- Power-Up/Down Glitch-free Bus Inputs and Outputs
- Short-Circuit Protection on Outputs
- RoHS Compliant
- ControlNet Vendor ID 806

DESCRIPTION

The SN65HVD61 is designed to meet the requirements for the driver and receiver circuitry of the ControlNet coaxial-based physical layer.

These devices are single-channel circuits with one transceiver for single node operation or distributed stand-alone applications.

The pull-or-pull transmitter circuit is designed to sink current from a center-tapped transformer, providing galvanic isolation from the shared bus.

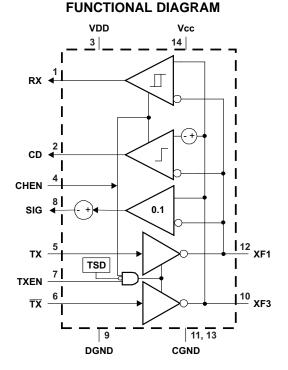
These devices incorporate a differential receiver (RX) with the 120 mV sensitivity needed by ControlNet industrial applications.

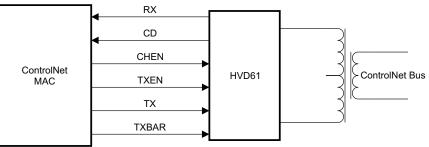
A secondary receiver (CD) detects the presence of a valid positive differential signal.

The third signal receiver function (SIG) provides a scaled analog output which is proportional to the differential voltage between XF1 and XF3. This output can be used for diagnostic purposes.

APPLICATIONS

- Industrial Networks
- Programmable Controllers
- Industrial Drives





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. ControlNet is a trademark of ODVA.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION

PART NUMBER	PACKAGE ⁽¹⁾	MARKED AS
SN65HVD61	D	
	DR ⁽²⁾	- 65HVD61

For the most current package and ordering information, see the Package Option Addendum at the end (1)of this document, or see the TI website at www.ti.com.

(2)R suffix indicates tape and reel

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

				VALUE	UNIT		
V _{CC}	Supply voltage ⁽²⁾ (3)						
V _{DD}	Supply voltage ⁽⁴⁾	Supply voltage ⁽⁴⁾					
	Logic input voltage range (TX,	Logic input voltage range (TX, TXBAR, TXEN, CHEN)					
	Bus terminal voltage range (XF	-22 to +22	V				
	Logic input current, (TX, TXBA	ogic input current, (TX, TXBAR , TXEN, CHEN)					
	Bus terminal current (XF1, XF3	Internally limited					
	Receiver output current (RX, C	Receiver output current (RX, CD)					
		Liveren Deck, Medel ⁽⁴⁾	Bus pins (XF1, XF3)	16	kV		
	Electro de la districtione	Human Body Model ⁽⁴⁾	All other pins	4	kV		
	Electrostatic discharge	Charged Device Model ⁽⁵⁾	Allinian	1500	V		
		Machine Model ⁽⁶⁾	All pins	200	V		
TJ	Junction temperature (see (7) t	Junction temperature (see ⁽⁷⁾ below regarding thermal shutdown)					

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DGND and CGND should be connected to a common ground plane external to the device. All voltage values, except differential I/O bus (2) voltages, are with respect to the ground plane

V_{CC} and V_{DD} lower limits are DC conditions, see application information regarding start-up transients. (3)

Tested in accordance JEDEC Standard 22, Test Method A114-A. (4)

(5)

Tested in accordance JEDEC Standard 22, Test Method C101. Tested in accordance JEDEC Standard 22, Test Method A115-A. (6)

(7)If the internal junction temperature exceeds 170°C, a thermal shutdown function will disable the transmitter.

DISSIPATION RATINGS

CIRCUIT BOARD MODEL ⁽¹⁾	RD $T_A \le 25^{\circ}C$ DERATING FACTOR ⁽²⁾ ABOVE $T_A = 25^{\circ}C$		T _A = 65°C	T _A = 100°C
Low-K	625 mW	5 mW/°C	425 mW	250 mW
High-K	1180 mW	9.5 mW/°C	800 mW	475 mW

(1) Tested in accordance with the Low-K or High-K thermal metric definitions of EIA/JESD51-3 for leaded surface mount packages. For additional information about JEDEC thermal models, see Texas Instruments Application Note Thermal Characteristics of Logic and Linear Packages using JEDEC PCB Designs (SZZA017).

This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow. (2)

RECOMMENDED OPERATING CONDITIONS

			MIN	NOM	MAX	UNIT
V_{CC}	Analog supply voltage ⁽¹⁾	4.5	5	5.5	V	
V_{DD}	Input/Output supply voltage ⁽²⁾	Input/Output supply voltage ⁽²⁾				
VIH	High-level logic input voltage	TY TYPAD TYPAL CUPN	0.7×VDD		VDD	
V _{IL}	Low-level logic input voltage	TX, TXBAR, TXEN, CHEN	0	().3×VDD	V
	Bus pin common-mode voltage	(VXF1 + VXF3) / 2	4.5		5.5	V
	Voltage at any bus terminal (XF1,	XF3)	-10		15	V
	Transmitter peak output current (X		130	150	mA	
I _{OH}	High-level logic output current		-8			A
I _{OL}	Low-level logic output current	RX, CD			8	mA
	Output current	SIG	-1		1	mA
T _A		$4.75 \text{ V} \le \text{V}_{CC} \le 5.25 \text{ V}$	-40		100	
	Operating free-air temperature	$4.5 \text{ V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{ V}$	-30		100	°C
TJ	Junction temperature				150	
	Signaling rate			10		Mbps
	Relative humidity (non-condensing			95%		

A power-shutdown feature keeps the device disabled when the voltage at V_{CC} is below 2.1 V.
 The I/O ring voltage for this device (V_{DD}) should be the same as the power supply voltage for the controller with which it interfaces. In the case where the voltages are different, designers must consider the logic threshold compatibility between devices.

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ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST COND	ITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
BUS PINS	S (XF1, XF3)						
V _{OL(TX)}	Transmitter output low voltage	Connect to V _{CC} through			0.9	1.2	V
V _{OH(TX)}	Transmitter output high voltage	37.5 Ω, ±1% resistor	V _{CC} -0.05	V _{CC}		v	
V _{O(OFF)}	Transmitter off noise level, XF3-XF1	R_L = 37.5 Ω, 0 to 20 MHz BW inputs idle, CHEN and TXEN				5	mV
V _{SW(PP)}	Receiver-to-bus reflection, peak-to-peak	R1=R2=50 Ω, C1=C2=15pF,	See Figure 3			200	mV
V _{TH+}	Positive-going differential input threshold voltage	4.5V < Vcm < 5.5V			35	120	mV
V _{TH-}	Negative-going differential input threshold voltage	4.5V < Vcm < 5.5V		-120	-35		mV
V _{hys}	Hysteresis voltage (V _{TH+} – V _{TH-})	4.5V < Vcm < 5.5V, RX output	t	50	70		mV
V _{CD}	Carrier detect threshold voltage, (XF3-XF1)	4.5V < Vcm < 5.5V		23	175	255	mV
	Pus terminal input lookage surrent	V _I = 10V, TXEN at 0V, Other input at –10V to 10V				1.2	mA
I	Bus terminal input leakage current	$V_I = -10V$, TXEN at 0V Other input at -10V to 10V		-1.7			ШA
I _{I(off)}	Bus terminal input leakage current	V_{CC} < 2V, V_{I} = -10V to 10V Other input at -10 V to 10 V	-1.7		1.2	mA	
l _{os}	Short-circuit output current	$0 < V_O < V_{CC}$	-400		400	mA	
R _{IN}	Bus terminal input resistance	$V_I = -10V$ to 10V, Other input	at CGND, DC	12			kΩ
C _{IN}	Differential input capacitance (XF1-to-XF3)	10 MHz AC test frequency, 1 HP4194A or equivalent imped $V_{CC} = 0V$		7	11	pF	
LOGIC IN	PUTS (TX, TXBAR, TXEN,CHEN)						
l _l	Logic input current	TX, TXBAR, TXEN, CHEN		-100		100	μA
I _{I(off)}	Logic input power-off current	V _{DD} at 0 V, TX,TXBAR, TXEN	I, CHEN		-100	100	μA
LOGIC OL	UTPUTS (RX, CD)	·					
V	Logic output voltage, high lovel	C _L = 15 pF		$0.8 \times V_{DD}$			V
V _{OH}	Logic output voltage, high level	$I_0 = -4 \text{ mA}, V_{DD} > 3V$	= -4 mA, V _{DD} > 3V				
V		C _L = 15 pF				$0.2 \times V_{DD}$	V
V _{OL}	Logic output voltage, low level	I _O = 4 mA				0.4	v
I _{OZ}	Logic output high-impedance-state current	RX, CD, 0 < V _O < V _{DD}		-20		20	μA
I _{O(off)}	Logic output power-off current	V _{DD} at 0 V, 0 < V _O < 5.5V		-1		1	mA
SIGNAL S	STRENGTH PIN (SIG)						
V _{SIG(0)}	SIG output voltage with zero differential input voltage	$R_L = 5 k\Omega$		1.125	1.25	1.375	V
		V _{ID} switching at 10 Mbps,	$4.75 \text{V} \leq \text{V}_{\text{CC}} \leq 5.25 \text{V}$			120	
GAIN	SIG gain ΔV _O /ΔV _{ID}	V _O measured with 20 MHz bandwidth, See Figure 10			140	mV/V	
POWER S	SUPPLY PINS (V _{CC} , CGND, VDD, DGND)						
	Analog supply current (dynamic)	CHEN and TXEN at logic high	n, No load		36	65	
lcc	Analog supply current, chip disabled	CHEN at logic low			1.8	3	mA
	Analog supply current, Lowest power conditions	CHEN at DGND, TX and TXBAR at V_{DD}			0.8	2	
	I/O supply current, I/O, dynamic	CHEN at logic high, no load				5	mA
IDD	I/O supply current, I/O, chip disabled	CHEN at logic low				105	μA

(1) All typical values are at 25°C and with a 5 V supply. For typical values with a 3.3V supply, refer to the TYPICAL CHARACTERISTICS curves.



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SWITCHING CHARACTERISTICS

over operating recommended operating conditions (unless otherwise noted)

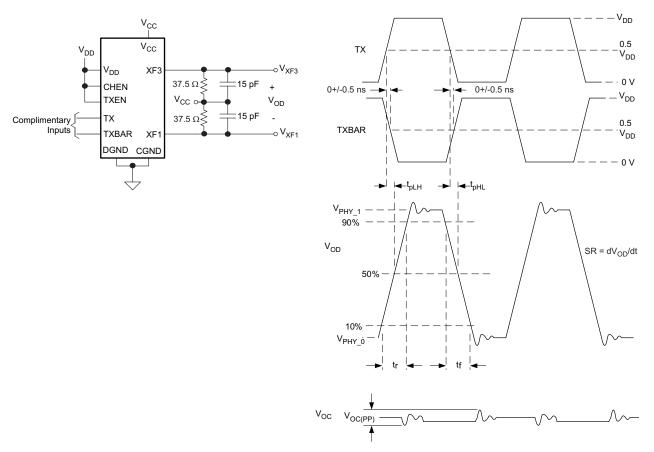
	PARAMETER	TEST CO	MIN	TYP	MAX	UNIT	
TRANS	/ ITTER						
t _r	Output rise time (10%-to-90%) differential				20	30	
t _f	Output fall time (90%-to-10%) differential			20	30		
t _{PLH}	Propagation delay time, low-to-high-level differential output	R _L = 37.5 Ω, C _L = 1			22	50	ns
t _{PHL}	Propagation delay time, high-to-low-level differential output	TXEN at logic high,	See Figure 1 ⁽¹⁾		24	50	115
t _{sk(p)}	Pulse skew, differential (XF3-XF1) t _{PLH} - t _{PHL}			2	5		
t _{OUT} SKEW	Output delay skew, $t_{\text{pON}} - t_{\text{pOFF}},$ single-ended outputs	R _L = 37.5 Ω, C _L = 1	0	7	12	ns	
t _{ON} -t _{OFF}	Symmetry, turn-on-time-to-turn-off-time, 10%/90%, each single-ended output	TXEN at logic high, See Figure 2		0	9	12	115
t _{PZL}	Propagation delay time, disabled-to-low-level output	R _L = 37.5 Ω, C _L = 15 pF, See	TXEN changing,			250	
t _{PLZ}	Propagation delay time, low-level-to-disabled-output		CHEN at VDD			400	ns
t _{PZL}	Propagation delay time, disabled-to-low-level output	_ Figure 4	CHEN changing,			400	115
t _{PLZ}	Propagation delay time, low-level-to-disabled-output		TXEN at VDD			400	
SR	Output differential slew rate	See Figure 1	0°C < T < 85°C			1	V/ns
	Transmit jitter, differential	10 Mbps Mancheste	er-code		2.5		ns
RECEIV	ERS (RX and CD)						
t _r	Output rise time (10%-to-90%)				2	20	
t _f	Output fall time (90%-to-10%)) (10 F) (2	20	
t _{PLH}	Propagation delay time, low-to-high-level output	$V_{ID} = \pm 2.5V,$ $R_{L} = 1 k\Omega,$			25	40	
t _{PHL}	Propagation delay time, high-to-low-level output	$C_{L} = 15 \text{ pF},$ See Figure 5			25	40	ns
		See Figure 5	RX		0.2	4.5	
t _{sk(p)}	Pulse skew t _{PLH} – t _{PHL}		CD			7	
t _{PZL}	Propagation delay time, high-impedance-to-low-level output	$V_{ID} = -2.5V, R_L = 11$	$k\Omega, C_L = 15 \text{ pF},$			1000	
t _{PLZ}	Propagation delay time, low-level-to-high-impedance output	See Figure 6				55	ns
t _{PZH}	Propagation delay time, high-impedance-to-high-level output	$V_{ID} = 2.5V, R_L = 1ks$	Ω, C _L = 15 pF,			1000	
t _{PHZ}	Propagation delay time, high-level-to-high- impedance output	See Figure 7				55	55 ns
	Receive jitter	10 Mbps Mancheste	er-code		0.5		

(1) 30 ns maximum represents the worst-case allowable rise/fall time when connected to a transformer-coupler network.

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PARAMETER MEASUREMENT INFORMATION

Figure 1. Transmitter Differential Switching Characteristics

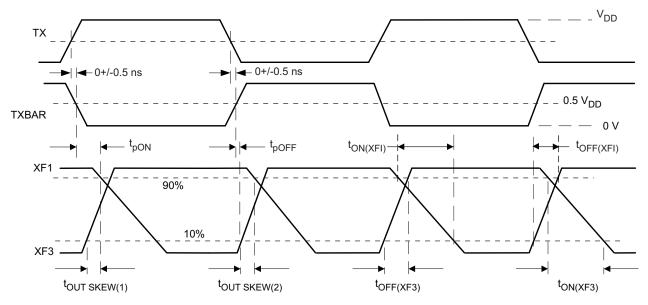
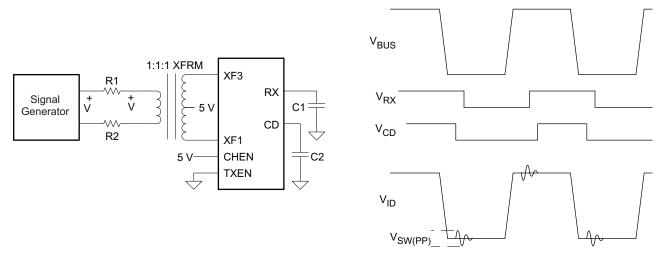


Figure 2. Transmitter Single-Ended Switching Characteristics



PARAMETER MEASUREMENT INFORMATION (continued)





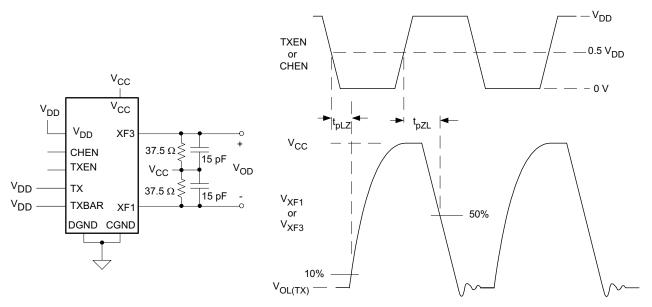


Figure 4. Transmitter Enable/Disable Test Circuits and Characteristics

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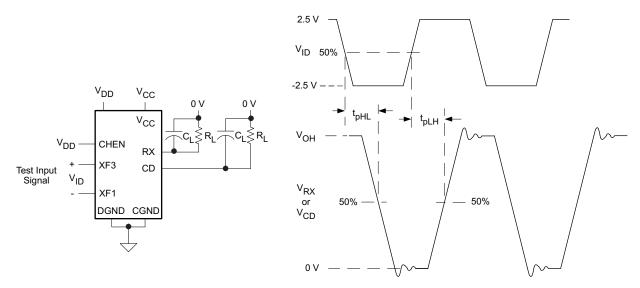


Figure 5. Test Circuit and Signal Waveforms, Receiver and Carrier Detect

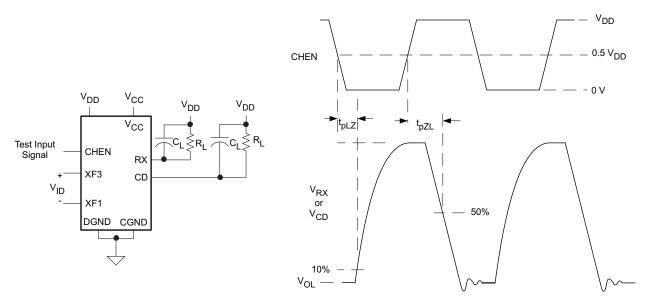


Figure 6. Test Circuit and Signal Waveforms, Receiver Enable and Disable With Low Bus Input



PARAMETER MEASUREMENT INFORMATION (continued)

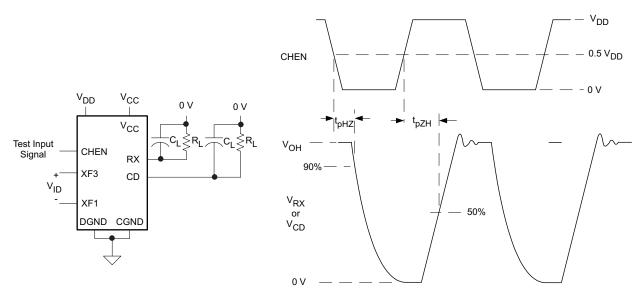


Figure 7. Test Circuit and Signal Waveforms, Receiver Enable and Disable With High Bus Input

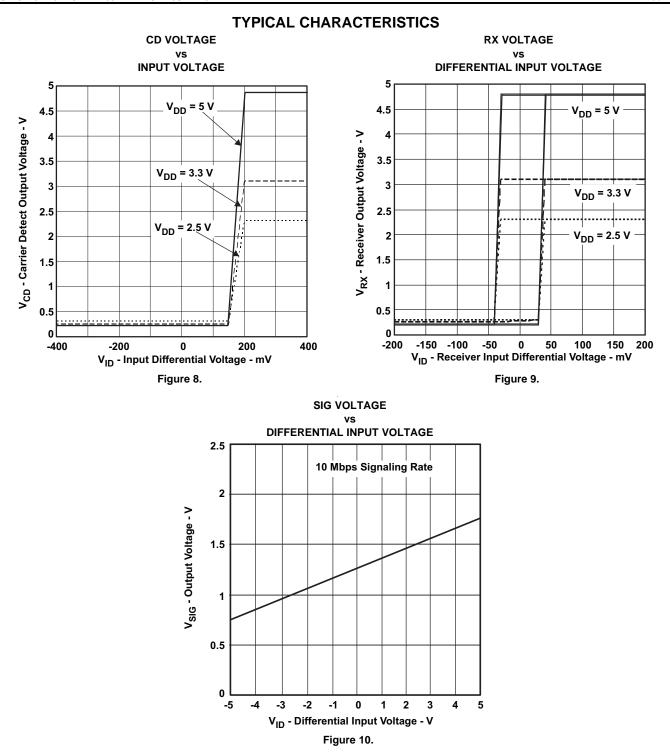
TRANSMITTER									
	INP	UTS		OUTP	UTS				
CHEN	TXEN	ТХ	TXBAR	XF1	XF3				
L or OPEN	Х	Х	Х	Z	Z				
	L or OPEN	Х	Х	Z	Z				
		L or OPEN	L or OPEN	Z	Z				
Н	н	L or OPEN	Н	Z	L				
		Н	L or OPEN	L	Z				
	H ⁽¹⁾	H ⁽¹⁾	H ⁽¹⁾	L ⁽¹⁾	L ⁽¹⁾				

Table 1. FUNCTION TABLES

(1) This combination is not supported and should be avoided in ControlNet applications

RECEIVER									
	INPUTS								
CHEN	XF1, XF3	CONDITION	RX						
L or OPEN	X	Chip disabled	Z						
	$(V_{XF3} - V_{XF1}) < V_{TH-}$	Negative signal	L						
н	$V_{TH-} < (V_{XF3} - V_{XF1}) < V_{TH+}$	No signal	?						
	$V_{TH+} < (V_{XF3} - V_{XF1})$	Positive signal	Н						

CARRIER DETECT									
	INPUTS								
CHEN	XF1, XF3	CONDITION	CD						
L or OPEN	Х	Chip disabled	Z						
	$(V_{XF3} - V_{XF1}) < V_{CD}$	Carrier not detected	L						
	$V_{CD} < (V_{XF3} - V_{XF1})$	Carrier detected	Н						



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APPLICATION INFORMATION

THERMAL SHUTDOWN

In most cases, the device's internal junction temperature will not reach the thermal shutdown temperature if operated within the recommended operating conditions. However, during fault conditions, such as driver short-circuit, the junction temperature may reach the thermal shutdown limit. This also depends on the thermal characteristics of the device mounting, the circuit board, and environmental factors. After the device reaches the thermal shutdown temperature, the driver outputs will be disabled, and the device will cool down. If the short-circuit is still present when the drivers are re-enabled, this *thermal shutdown cycle* will repeat until the short-circuit fault is removed.

For long-term reliability, the package power dissipation must not exceed the values in the data sheet POWER DISSIPATION RATINGS for extended periods.

POWER-UP TRANSIENTS

The absolute maximum ratings for Vcc and Vdd specify the limits for these supplies. During initial power-on, these supply voltages may instantaneously drop below the given lower limit. Designers should consider that diodes in the circuitry will begin to turn on if the voltage becomes too negative, and that damage may occur if these diodes dissipate significant power internal to the device. The actual threshold for possible damage is a function of both undervoltage magnitude and undervoltage transient duration. Further, the allowable undervoltage transient conditions depend on factors such as device junction temperature and power supply source impedance.

THERMAL CHARACTERISTICS OF IC PACKAGES

Junction-to-Ambient Thermal Resistance (θ_{JA}) is defined as the difference in junction temperature to ambient temperature divided by the operating power. θ_{JA} is NOT a constant and is a strong function of

- the PCB design (50% variation)
- altitude (20% variation)
- device power (5% variation)

 θ_{JA} can be used to compare the thermal performance of packages if the specific test conditions are defined and used. Standardized testing includes specification of PCB construction, test chamber volume, sensor locations, and the thermal characteristics of holding fixtures. θ_{JA} is often misused when it is used to calculate junction temperatures for other installations.

TI uses two test PCBs as defined by JEDEC specifications. The low-k board gives average in-use condition thermal performance and consists of a single trace layer 25 mm long and 2-oz thick copper. The high-k board gives best case in-use condition and consists of 2 1-oz buried power planes with a single trace layer 25 mm long with 2-oz thick copper. A 4% to 50% difference in θ_{JA} can be measured between these two test cards

Junction-to-case thermal resistance (θ_{JC}) is defined as difference in junction temperature to case divided by the operating power. It is measured by putting the mounted package up against a copper block cold plate to force heat to flow from die, through the mold compound into the copper block.

 θ_{JC} is a useful thermal characteristic when a heatsink is applied to package. It is NOT a useful characteristic to predict junction temperature as it provides pessimistic numbers if the case temperature is measured in a non-standard system and junction temperatures are backed out. It can be used with θ_{JB} in 1-dimensional thermal simulation of a package system.

Junction-to-board thermal resistance (θ_{JB}) is defined to be the difference in the junction temperature and the PCB temperature at the center of the package (closest to the die) when the PCB is clamped in a cold-plate structure. θ_{JB} is only defined for the high-k test card.

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 θ_{JB} provides an overall thermal resistance between the die and the PCB. It includes a bit of the PCB thermal resistance (especially for BGA's with thermal balls) and can be used for simple 1-dimensional network analysis of package system.

	JEDEC High-K Model	JEDEC Low-K Model
θ _{JA}	105.7°C/W	199.5°C/W
θ _{JB}	52.3	52.3
θ _{JC}	56.32°C/W	56.32°C/W

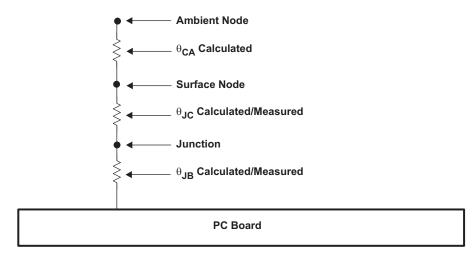


Figure 11. Thermal Resistance

Additional information about thermal metrics for integrated circuits is available in the Texas Instruments Application Note *IC Package Thermal Metrics* (SPRA953).

ControlNet APPLICATION

In a typical ControlNet application, several nodes will be connected to a common bus, as shown in Figure 12. At any time, only one node should actively drive the bus; all active nodes continually receive the bus state. The node which is actively driving the bus will sink current through either the XF1 or XF3 terminal, causing the voltage on the bus to be either differential high or differential low.

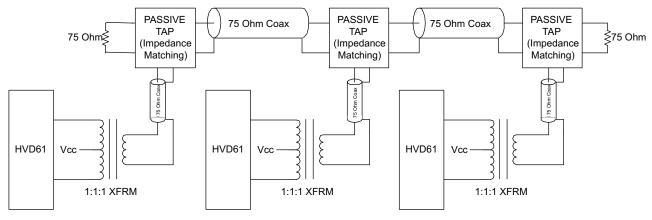


Figure 12. Typical ControlNet Application



SYSTEM-LEVEL EMC PROTECTION

The ControlNet network is intended to operate reliably in harsh industrial environments. At a system level, the network is tested according to several international electromagnetic compatibility (EMC) standards. The requirements are summarized in the Table 2 and Figure 13.

EMC STANDARD	DESCRIPTION OF TEST METHOD	LEVEL					
IEC 61000-4-2	Electro Static Discharge (ESD) Immunity	6 kV Contact 8 kV Air-Gap					
IEC 61000-4-3	Radiated Radio Frequency (RF) Immunity	10V/m at 80 MHz to 2.7GHz					
IEC 61000-4-4	Fast Transients / Burst Immunity	1 kV					
IEC 61000-4-5	Surge Immunity	1 kV					
IEC 61000-4-6	Conducted Radio Frequency (RF) Immunity	10V at 150 kHz to 80 MHz					



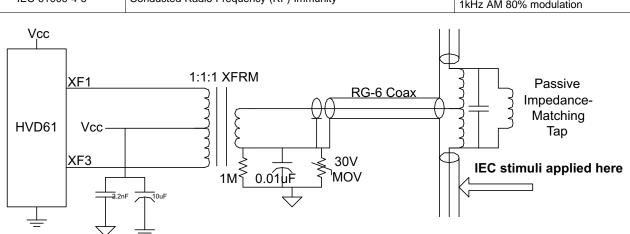


Figure 13. Simplified Test Set-Up for EMC Standards

DRIVER FUNCTIONS

The ControlNet standard requires the transmitter to generate a signal with nominal amplitude of 8.2Vpp into a 37.5 Ω load. This applies to the double-terminated coax bus as shown in Figure 12. Rise and fall times should not exceed 30 nsec, and the signal slew rate should not exceed 1 V/nsec. Transmit signal distortion (ringing, droop, overshoot) should not exceed 10% of the peak-to-peak amplitude.

RECEIVER FUNCTIONS

The function of the primary receiver (RX) and the carrier detect (CD) depends on the signals XF1 and XF3. The purpose of RX is to indicate the status of the two ControlNet bus lines, based on the signals XF1 and XF3. If the voltage at XF3 is greater than the voltage at XF1, then the bus state is positive, and RX should output a HIGH voltage. This corresponds to a Phy_1 symbol. If the voltage at XF3 is less than the voltage at XF1, then the bus state is negative, and RX should output a LOW voltage. This corresponds to a Phy_0 symbol. See Figure 14. Note that the allowable variation in V_{TH-} , V_{TH+} , and V_{CD} is specified in the ELECTRICAL CHARACTERISTICS table.



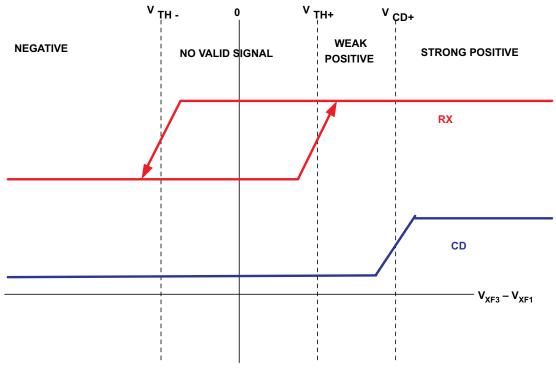


Figure 14. RX and CD Functions

SIGNAL STRENGTH OUTPUT

Vsig should be sampled at the beginning of a transmission in the preamble portion of the ControlNet Frame. This portion is the same for all nodes with the exception of the amplitude. Sampling Vsig in the preamble will provide the most consistent measurement. Further oversampling coupled with multiple frame sampling may provide further cable diagnostics such as identifying reflections due to cable breaks. By sampling multiple times in the preamble of a packet the distance to the break or short may be calculated.



Page

REVISION HISTORY

NOTE: Page numbers of current version may differ from previous versions.

Changes from Revision C (May 2007) to Revision D Changed ControlNet is a trademark of ControlNet International, Ltd to ControlNet is a trademark of ODVA 1 Changed Bus pin common-mode voltage MIN spec. from "4.75V to "4.5V" and MAX spec. from "5.25V to "5.5V" in Added second GAIN spec with conditions of $4.5V \le V_{CC} \le 5.5V$ in the ELEC CHARA TABLE, and added 140 mV/V



10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65HVD61D	ACTIVE	SOIC	D	14	50	RoHS & Green	Call TI NIPDAU	Level-1-260C-UNLIM	-40 to 100	65HVD61	Samples
SN65HVD61DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 100	65HVD61	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGE MATERIALS INFORMATION

Texas Instruments

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal	
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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65HVD61DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

5-Jan-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65HVD61DR	SOIC	D	14	2500	853.0	449.0	35.0



5-Jan-2022

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN65HVD61D	D	SOIC	14	50	506.6	8	3940	4.32

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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